

NOT RECOMMENDED FOR NEW DESIGN USE DMN2710UTQ



DMG1012TQ

N-CHANNEL ENHANCEMENT MODE MOSFET

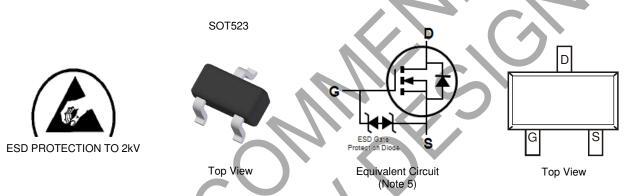
Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMG1012TQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT523
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Alloy 42 Lead-Frame. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)



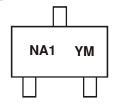
Ordering Information (Note 4)

Part Number	0:	ualification	Dockago	Packing		
Part Number	4	namication	Package	Qty.	Carrier	
DMG1012TQ-7	A	Automotive	SOT523	3000	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Hallogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
- 5. The ESD gate protection diode is only designed to protect against ESD events. No gate-source voltage greater than the maximum V_{GSS} rating (given on page 2) can be applied.

Marking Information



NA1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022) M = Month (ex: 2 = February)

Date Code Key

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	J	K	L	М	N	0	Р	R	S	T	U	٧
Month	Jan	Feb	Mar	Apr	Mav	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteris	tic		Symbol	Value	Unit
Drain-Source Voltage			VDSS	20	V
Gate-Source Voltage			V _{GSS}	±6	V
Continuous Drain Current (Note 6) Steady $T_A = +25^{\circ}C$ $T_A = +85^{\circ}C$			lo	0.63 0.45	А
Pulsed Drain Current			I _{DM}	3	Α

Thermal Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	PD	0.28	W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	452	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

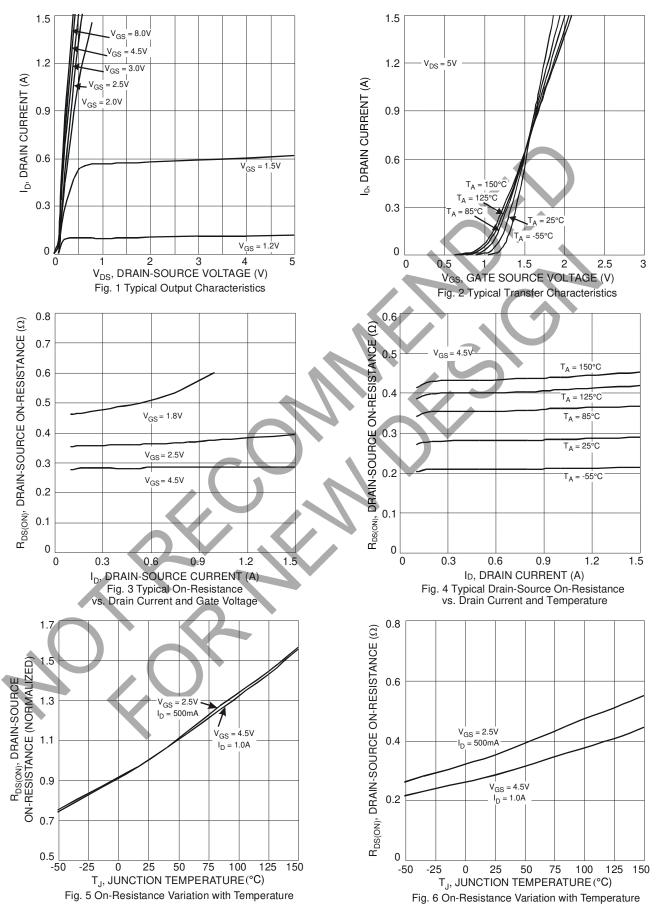
Electrical Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	1	V	V	$V_{GS} = 0V$, $I_D = 250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	IDSS			100	nA	V _{DS} = 20V, V _{GS} = 0V	
Gate-Source Leakage	lgss	1	l	±1.0	μΑ	$V_{GS} = \pm 4.5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	0.5	_	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		0.3	0.4		$V_{GS} = 4.5V, I_D = 600mA$	
Static Drain-Source On-Resistance	RDS(ON)	_	0.4	0.5	Ω	$V_{GS} = 2.5V, I_D = 500mA$	
		7	0.5	0.7		V _{GS} = 1.8V, I _D = 350mA	
Forward Transfer Admittance	Y _{fs}	—	1.4	_	S	V _{DS} = 10V, I _D = 400mA	
Diode Forward Voltage	VsD	_	0.7	1.2	V	V _G S = 0V, I _S = 150mA	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	1	60.67		pF	101/1/	
Output Capacitance	Coss	1	9.68		pF	V _{DS} = 16V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	1	5.37		pF	1 – 1.01/11/2	
Total Gate Charge	Q_g		736.6	_	рC	451/1/4	
Gate-Source Charge	Qgs	_	93.6	_	рС	$V_{GS} = 4.5V, V_{DS} = 10V,$ $I_{D} = 250 \text{mA}$	
Gate-Drain Charge	Q _{gd}	_	116.6	_	рC	1D = 250MA	
Turn-On Delay Time	t _{D(ON)}	_	5.1	_	ns		
Turn-On Rise Time	t _R	_	7.4	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$	
Turn-Off Delay Time	tD(OFF)	_	26.7	_	ns	$R_L = 47\Omega$, $R_G = 10\Omega$, $I_D = 200 \text{mA}$	
Turn-Off Fall Time	tF	_	12.3	_	ns	10 - 200111A	

Notes:

- Device mounted on FR-4 PCB, with minimum recommended pad layout.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.







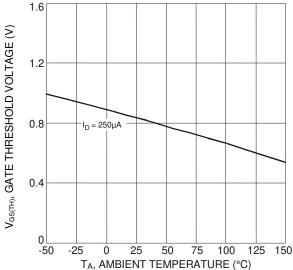
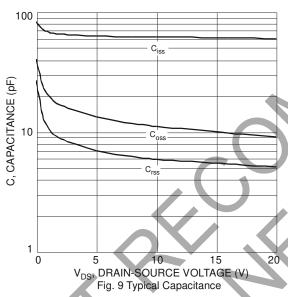


Fig. 7 Gate Threshold Variation vs. Ambient Temperature



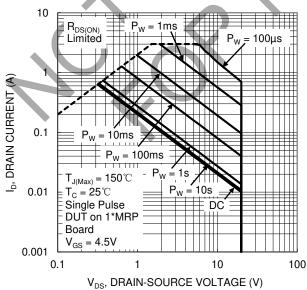


Fig. 11 SOA, Safe Operation Area

Fig. 8 Diode Forward Voltage vs. Current

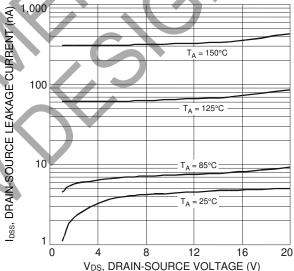
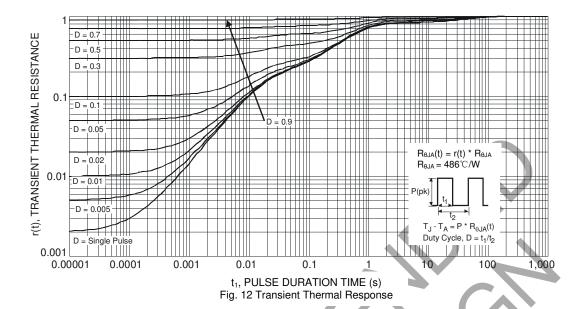


Fig. 10 Typical Drain-Source Leakage Current vs. Drain-Source Voltage



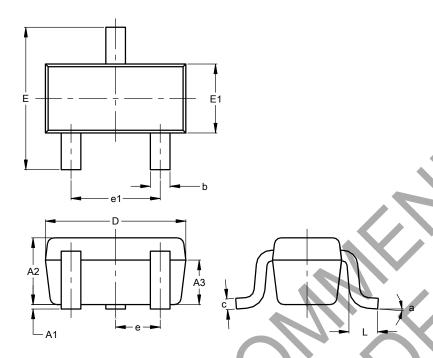




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523

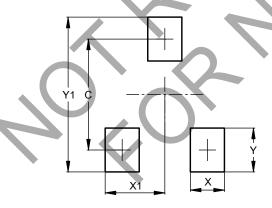


	SOT523							
Dim	Min	Max	Тур					
A1 .	0.00	0.10	0.05					
A2	0.60	0.80	0.75					
A 3	0.45	0.65	0.50					
b	0.15	0.30	0.22					
C	0.10	0.20	0.12					
ם	1.50	1.70	1.60					
	1.45	1.75	1.60					
ET	0.75	0.85	0.80					
е	e 0.50 BSC							
e1	0.90	1.10	1.00					
L	0.20	0.40	0.33					
а	0°		8°					
A	All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value (in mm)			
С	1.29			
Х	0.40			
X1	0.70			
Υ	0.51			
Y1	1.80			



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